

correspond to a value of  $\alpha$  as defined by relation (5) in the text of 77 °K. If one instead fits to the glass-Mo<sub>0.99</sub> Fe<sub>0.01</sub>-Pb data, one obtains the value of 148 °K quoted in the text.

<sup>20</sup>A. S. Edelstein, Phys. Rev. 180, 505 (1969).  
<sup>21</sup>H. V. Culbert and A. S. Edelstein, Solid State Commun. 8, 445 (1970).  
<sup>22</sup>J. S. Kouvel, J. Phys. Chem. Solids 21, 57 (1961).  
<sup>23</sup>Y. Miyako, T. Watanabe, and M. Watanabe, Phys. Rev. 182, 495 (1969).  
<sup>24</sup>J. A. Careaga, B. Dreyfus, R. Tournier, and L. Weil *Proceedings of the Tenth International Conference on Low Temperature Physics, Moscow, USSR, 1966* (VINITI Publishing, Moscow, 1967), Vol. IV, p. 284, paper A70.  
<sup>25</sup>R. W. Schmitt and I. S. Jacobs, J. Phys. Chem. Solids 3, 324 (1957).  
<sup>26</sup>P. G. de Gennes and G. Sarma, J. Appl. Phys. 34, 1380 (1963).  
<sup>27</sup>J. J. Hauser, Phys. Rev. Letters 23, 374 (1969).  
<sup>28</sup>We are indebted to J. H. Condon for making this experiment.  
<sup>29</sup>C. A. Domenicali and E. L. Christenson, J. Appl. Phys. 32, 2450 (1961).  
<sup>30</sup>D. R. Hamann, Phys. Rev. B 2, 1373 (1970).  
<sup>31</sup>B. T. Matthias, H. Suhl, and E. Corenzwit, Phys. Rev. Letters 1, 92 (1958).  
<sup>32</sup>K. H. J. Buschow and H. J. Van Daal, Phys. Rev. Letters 23, 408 (1969).  
<sup>33</sup>H. J. Williams, J. H. Wernick, E. A. Nesbitt, and R. C. Sherwood, J. Phys. Soc. Japan Suppl. 17, 91 (1962).  
<sup>34</sup>W. M. Swift and W. E. Wallace, J. Phys. Chem. Solids 29, 2053 (1968).  
<sup>35</sup>We are indebted to R. C. Sherwood for the magnetic measurements made on CeAl<sub>2</sub>.  
<sup>36</sup>R. W. Hill and J. M. Machado da Silva, Phys. Letters 30A, 13 (1969).  
<sup>37</sup>G. J. Van den Berg, in *Progress in Low Temperature Physics*, edited by C. J. Gorter (North-Holland, Amsterdam, 1964), Vol. IV, p. 194.  
<sup>38</sup>A. B. Kaiser and M. J. Zuckermann, Phys. Rev. B 1, 229 (1970).  
<sup>39</sup>W. L. McMillan, Phys. Rev. 175, 537 (1968).  
<sup>40</sup>M. A. Woolf and F. Reif, Phys. Rev. 137, A557 (1965).  
<sup>41</sup>J. J. Hauser, Physica 2, 247 (1966).  
<sup>42</sup>J. J. Hauser, Phys. Rev. 164, 558 (1967).  
<sup>43</sup>A. S. Edelstein, Phys. Rev. Letters 19, 1184 (1967); Phys. Rev. 180, 505 (1969).  
<sup>44</sup>T. N. Mihalisin, D. P. Snowden, and P. M. Chaikin (unpublished).

## Interaction of 9.3-GHz Longitudinal Phonons with Electrons in Superconducting Films

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Previous studies of the interaction of longitudinal phonons with superconducting Al-Pb junctions have been extended to include nonuniform strains, arising when the thicknesses of the metal films are not negligible compared to the wavelength of the sound and/or when the wave front makes a small angle  $\theta$  with the plane of the junction. It is found that nonuniform strains produce an electric field proportional to the strain gradient inside the "local" superconducting Al film. This result confirms the theories of Dessler *et al.*, Herring, and Harrison who calculated the gravity-induced electric fields. The strain-induced field in the aluminum excites electromagnetic waves in the junction which are enhanced due to the traveling-wave interaction in the strip line formed by the junction. The electromagnetic field gives rise to an extra tunneling current which exhibits resonant behavior as a function of the angle  $\theta$ . In the "nonlocal" Pb films, the interaction of the electrons with the strain wave is described by absorption and emission of phonons, and the extra tunneling current due to this process is essentially independent of  $\theta$ . This behavior enables us to separate the extra current due to the Al film and that due to the Pb film. The agreement between theory and experiment is found satisfactory.

### I. INTRODUCTION

It was shown several years ago that the interaction between sound waves and electrons in metals can be observed directly by measuring the phonon-induced current in superconducting tunnel junc-

tions.<sup>1-3</sup> In the case of compressional waves,<sup>1,3</sup> this extra current was attributed to a relative motion of the Fermi energies in the two metals due to the compressional strain. In the interpretation of the above experiments it was assumed that the strain was spatially uniform. The present work,

preliminary results of which have recently been reported<sup>4</sup> by the authors, concerns itself with the more general case of a spatially nonuniform strain. The question whether a nonuniform strain gives rise to an electric field outside a metal received considerable attention over the last few years. This interest arose in connection with the attempt of Witteborn and Fairbank<sup>5</sup> to measure the gravitational force acting on an electron. It was pointed out by Dessler *et al.*<sup>6</sup> and Herring<sup>7</sup> that the nonuniform strain set up by gravity in the copper cylinder used in this experiment to shield the electron gives rise to an electric field outside the metal. The force on the electron outside the metal due to this field should have been in the direction of the gravitational force and about four orders of magnitude larger. However, no such force was observed experimentally. To demonstrate directly the presence of an electric field inside a metal due to a nonuniform strain, Beams<sup>8</sup> measured the radial electrical potential gradient across a Duraluminum rotor spinning at high speed. He found a reasonable agreement with the theoretical predictions, but "no clear-cut theoretical interpretation of the experiment was possible." More recently, Craig<sup>9</sup> measured semiquantitatively the effect of uniform stress on the contact potential of several metals. The observed shifts in contact potentials were found to be in order-of-magnitude agreement with the theories that apply for the nonuniform gravitational strain,<sup>6,7</sup> provided one can assume that the gravitational stress is equivalent to a uniform hydraulic stress.

In the present work we treat the case of a nonuniform strain which arises when the thickness of the metal films is not negligible compared to the wavelength of the sound and/or if the wave front is not completely parallel to the film surface. We distinguish between two different cases,  $q\xi > 1$  and  $q\xi < 1$ , where  $q$  is the sound wave number and  $\xi$  is the Pippard coherence distance.<sup>10</sup> (For a normal metal the above conditions are replaced by  $ql \leq 1$ , where  $l$  is the mean free path.) In the case of  $q\xi < 1$ , local electrodynamics applies and the spatially varying strain produces an electrostatic potential in the metal proportional to the strain.<sup>6,7</sup> A small angle  $\theta$  between the sound wave vector and the normal to the film results in an extremely fast potential wave in the plane of the film. The velocity of this wave is  $v/\sin\theta$ , where  $v$  is the sound velocity. The potential wave induces electromagnetic waves in the junction, the latter acting as a strip line.<sup>11</sup> When the velocity of the potential wave equals the propagation velocity of an electromagnetic wave in the strip line, resonant coupling occurs due to traveling-wave interaction, and the induced electromagnetic field achieves its maximum amplitude. The presence of the electromagnetic

field was detected by its effect on the tunneling current.

In the case  $q\xi > 1$ , the phonon-electron interaction is described in terms of phonon emission and absorption. The extra tunneling current due to this process has recently been calculated by Cohen.<sup>12</sup> This current is essentially independent of the angle  $\theta$ , whereas the current due to the electrostatic potential wave is strongly angle dependent. This permitted us to distinguish between the two currents, and to explain an anomaly in the observed magnitude and temperature dependence reported earlier.<sup>3</sup>

## II. THEORY

It has been found by Dayem and Martin<sup>13</sup> that the interaction of a microwave electric field with a superconducting tunnel junction gives rise to an extra tunneling current  $\delta I$ . Tien and Gordon<sup>14</sup> calculated this extra current due to a microwave field  $E$  across a junction and obtained

$$\delta I = (we/2hv)^2 f |E|^2, \quad (1a)$$

where  $w$  is the insulator thickness,  $h$  is Planck's constant, and  $e$  is the magnitude of the electronic charge. The coefficient  $f$  depends on the dc current-voltage ( $I$ - $V$ ) characteristic of the tunnel junction and on the microwave frequency  $\nu$ :

$$f = I(V + h\nu) + I(V - h\nu) - 2I(V). \quad (1b)$$

Equation (1) is valid for fields small enough so that  $|E|^2 \ll (hv/we)^2$ . It was later found that such an extra current can be induced also by compressional sound waves.<sup>1-3</sup> It was shown that for the case of a uniform compressional strain the extra current  $\delta I_s$  is given by Eq. (1), provided that  $E$  is replaced by an effective field  $E_s$  derived from the difference between the electrochemical potentials of the two metals,

$$E_s = [(sC)_1 - (sC)_2]/we. \quad (2)$$

Here  $sC$  is the product of the strain and the deformation potential in the two metals comprising the tunnel junction.

We now proceed to treat the more general case of an extra current due to a spatially nonuniform strain. The geometry we wish to consider is a metal-insulator-metal sandwich on an insulating substrate shown schematically in Fig. 1. We assume that the spatial variation in the strain arises because of the finite thicknesses of the metal films and because of the non-normal incidence of the sound wave. We show here that in this case the sound wave excites an electromagnetic wave in the tunnel junction. The electromagnetic field  $\vec{E}$  in the insulator has a component normal to the junction. This component  $E_x$  also induces an extra current and has to be added to  $E_s$ . Because of the spatial variation of  $E_x$  and  $E_s$ ,  $\delta I_s$  is given now by

$$\delta I_s = (we/2h\nu)^2 (f/a) \int_a |E_x + E_s|^2 da \quad (3)$$

rather than by Eq. (1). The coefficient  $f$  in Eq. (3) is still given by Eq. (1b), and the integration is performed over the area  $a$  of the junction.

We now proceed to calculate the fields  $E_s$  and  $E_x$  which enter into Eq. (3). Let the incident acoustic wave propagate in the  $x$ - $z$  plane making an angle  $\theta$  with the positive  $x$  direction (see Fig. 1). The wave is totally reflected at the free surface of metal 1, while the other interfaces introduce only partial reflections, insofar as there exists an acoustic mismatch between the respective media. We restrict ourselves to the case of very small angles ( $\theta < 1^\circ$ ), the situation encountered experimentally. In that case the compressional strain  $s$  can be expressed in each medium as a product of a running wave in the  $z$  direction and a standing wave in the  $x$  direction:

$$s(x, z) = s_0 e^{i(\omega t - q_x x)} (e^{-i q_x x} + e^{i(q_x x + \beta)}) / (1 + e^{i\beta}). \quad (4)$$

Here  $q_x$  and  $q_z$  are the  $x$  and  $z$  components of the wave vector  $\vec{q}$  in each medium,  $t$  is the time, and  $\omega = 2\pi\nu$ . The strain amplitude  $s_0$  and the phase  $\beta$  in the different media are determined by the various reflections. Sound absorption is neglected in Eq. (4), i.e.,  $\vec{q}$  is real.

The nonuniform strain gives rise to an electrostatic potential  $\varphi$ . At sufficiently low sound frequencies, quasithermal equilibrium is established in each of the metal films and one can define a time varying electrochemical potential. This concept is valid as long as the scale of variation of the electromagnetic field is large compared to the mean free path  $l$ , in the case of a normal metal, or the Pippard coherence length<sup>10</sup>  $\xi$ , in the case of a superconductor, i.e.,

$ql \ll 1$  for a normal metal,

$q\xi \ll 1$  for a superconductor.

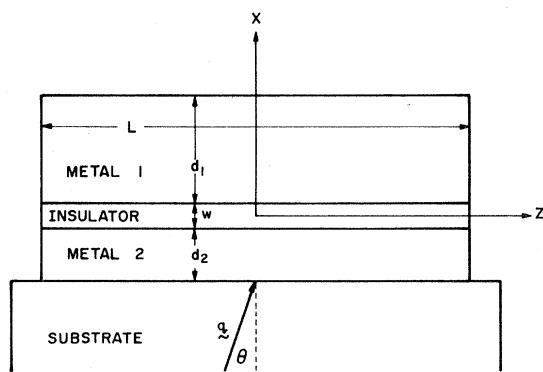


FIG. 1. Schematic representation of tunnel junction. The slightly oblique incidence of the compressional wave is indicated by the wave vector  $\vec{q}$ .

Here

$$1/\xi = 1/\xi_0 + 1/l,$$

where  $\xi_0$  is the intrinsic coherence length. A lower limit to the frequency is set by the requirement that in order to be able to treat each metal separately, independent of the other metal, we require  $\omega\tau \gg 1$ , where  $\tau$  is the capacitive time constant of the junction.<sup>15</sup>

The electrochemical potential  $\mu$  is defined as

$$\mu = \mu_F - e\varphi, \quad (5)$$

where  $\mu_F$  is the chemical potential. The electrostatic potential  $\varphi$  is proportional to the difference between  $s$  and its average value  $\langle s \rangle$  over the volume of the metal,

$$e\varphi = C(s - \langle s \rangle), \quad (6)$$

where  $C$  is defined as the deformation potential. (For a free-electron gas,  $C = -\frac{2}{3}\mu_F$ .) The chemical potential  $\mu_F$  is given by

$$\mu_F(s) = \mu_F(0) + Cs, \quad (7)$$

where  $\mu_F(0)$  is the chemical potential in the absence of strain.

Substituting Eqs. (6) and (7) into Eq. (5) we obtain for  $\mu$

$$\mu(s) = \mu(0) + C\langle s \rangle. \quad (8)$$

The different quantities in Eqs. (5)–(8) are shown schematically in Fig. 2, both in the presence and in the absence of a strain wave. The effective field  $E_s$  is given by

$$E_s = (\mu_1 - \mu_2)/we. \quad (9)$$

From this last equation and Eq. (8) it now follows that in the case of a nonuniform strain Eq. (2) for  $E_s$  has to be replaced by

$$E_s = [(C\langle s \rangle)_1 - (C\langle s \rangle)_2]/we. \quad (10)$$

We now turn to calculate the electric field  $E_x$  in the insulator. It was first pointed out by Pippard<sup>11</sup> that a strip line consisting of a metal-insulator-metal sandwich will propagate an electromagnetic wave but with a reduced velocity. Swihart<sup>11</sup> performed detailed calculations of the electromagnetic propagation constant  $\gamma_p$  of the strip line in terms of the microwave surface impedances of the two metals. The present calculation departs from that of Swihart in that we include the field due to the electrostatic potential  $\varphi$  in each metal. We express the electromagnetic field in the insulator by the vector potential  $\vec{A}(x, z, t)$ , and we look for solutions of the form

$$\vec{A} = \vec{A}(x) e^{i(\omega t - \gamma_p z)}. \quad (11)$$

We apply the usual boundary conditions, i.e., the continuity of the parallel components of the electric

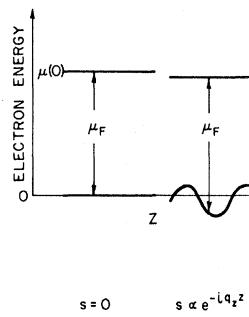


FIG. 2. Schematic representation of the electrochemical potential  $\mu$ , the chemical potential  $\mu_F$ , and the electrostatic potential  $\varphi$ , both in the presence and absence of a compressional wave  $s$ .

and magnetic fields across the insulator-metal interfaces. We solve the equations for  $\gamma$  and obtain a solution which consists of two characteristic waves propagating in the positive and negative  $z$  direction, respectively, with wave number  $\gamma_p$  and a driven wave having the same wave number  $q_x$  as the strain. We take into account the finite length  $L$  of the strip line in the  $z$  direction by requiring the vanishing of the magnetic field at the boundaries  $z = \pm \frac{1}{2}L$ . From this latter condition we determine the amplitudes of the characteristic waves. The detailed mathematical treatment is given in the Appendix. The solution for  $E_x$  is given by

$$E_x = [(Cs_0)_2 - (Cs_0)_1] q_x^2 (e^{-i q_x z} - (\gamma_p/q_x \sin \gamma_p L) \{ \sin[\frac{1}{2}(q_x - \gamma_p)L] e^{i \gamma_p z} + \sin[\frac{1}{2}(q_x + \gamma_p)L] e^{-i \gamma_p z} \}) [we(q_x^2 - \gamma_p^2)]^{-1}, \quad (12)$$

where  $\gamma_p$  is given by Eq. (A19) and we have omitted in Eq. (12) the factor  $e^{i \omega t}$ .

In the case of  $q\xi > 1$ , the assumption of quasi-thermal equilibrium is no longer valid and the interaction of electrons with the sound wave is described via absorption and emission of phonons. This case has been treated theoretically by Cohen,<sup>12</sup> who finds an extra current  $\delta I_q$  with a similar bias and strain dependence as  $\delta I_s$ .

### III. EXPERIMENT

The tunnel junctions were vacuum deposited on one end of an  $X$ -cut quartz rod. Most of the experiments were done with Al-Pb junctions. An aluminum film a few hundred Å thick was evaporated first, next the film was exposed to dry oxygen at atmospheric pressure for 1 min and then a thick (several thousand Å) lead film was deposited on top. In order to increase the transition temperature of the aluminum films above 2 °K, oxygen was continuously fed into the system during the Al evaporation so as to maintain the pressure at  $5-6 \times 10^{-5}$  Torr.<sup>16</sup> The lead was evaporated at a pressure of  $10^{-6}$  Torr. Typical dimensions of the junctions were  $0.1 \times 0.27$  cm. The quartz rods were 0.3 cm

in diam and 2 cm long with optically polished end faces parallel within 4 sec of an arc. The other end of the quartz rod was inserted into a reentrant microwave cavity. The rod was clamped at a position close to its entrance into the cavity and a bending moment could be applied perpendicular to the axis of the rod by means of three spring loaded Teflon pins situated 120° apart. The arrangement is shown schematically in Fig. 3. The cavity was immersed in liquid helium and the temperature could be varied by reducing the ambient pressure.

The cavity was excited at its resonant frequency  $\nu = 9.3$  GHz with 120-W microwave pulses of 1-μsec duration. A microwave pulse produced a compressional sound pulse which propagated along the length of the quartz rod. The measured conversion efficiency of microwave to sound energy was 50 dB. The sound pulse was reflected both at the tunnel junction surface and at the cavity end of the rod and bounced back and forth many times producing a train of sound echoes in the rod. The angle  $\theta_n$  between the sound wave vector  $\vec{q}$  and the normal to the junction is determined by the echo number  $n$  and by the angle  $\theta_1$  between the end faces of the rod:

$$\theta_n = (2n - 1) \theta_1, \quad (13)$$

and the corresponding value of  $q_x$  is

$$q_x = q \sin \theta_n \approx q \theta_1 (2n - 1). \quad (14)$$

The angle  $\theta_1$  could be varied by the application of the bending moment to the rod. Typically the magnitude of  $\theta_1$  was less than 60 sec. Coincident with the arrival of the sound echoes at the tunnel junction, an extra tunneling current  $\delta I$  was observed. This current was measured by means of a low-noise pulse amplifier and displayed on an oscilloscope as a function of time. A detailed description of the pulse detection and microwave techniques is given in Ref. 3. Figure 4 shows two typical oscillograms of  $\delta I$ , taken on the same junction, holding the temperature and microwave power constant, but

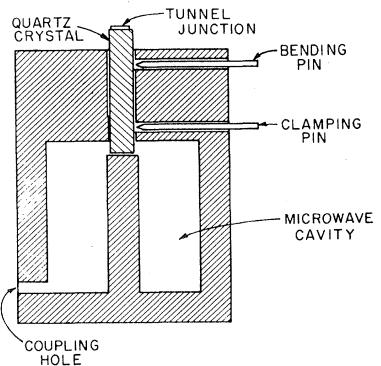


FIG. 3. Schematic representation of the reentrant microwave cavity and the bending arrangement.

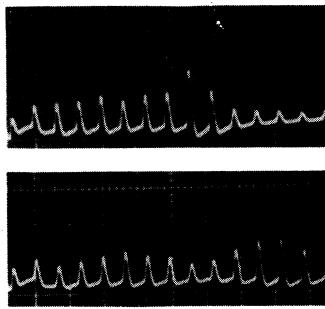


FIG. 4. Two oscilloscopes taken on the same junction at constant microwave power and temperature  $T = 1.36^\circ\text{K}$ . The upper one was taken with a bending moment applied to the quartz rod larger than that for the lower oscilloscope. The horizontal scale is 10  $\mu\text{sec}/\text{div}$ .

changing the applied bending moment. The dc-voltage bias was set for a maximum  $\delta I$  (see Ref. 4 for the bias dependence of  $\delta I$ ). The echo envelopes in both oscilloscopes exhibit a maximum which occurs at different echo number in each oscilloscope. The positions of the maxima were found to be directly related to the applied moments. Increasing the bending moment resulted in a motion of the modulation maximum to lower echo number. In Fig. 5 are plotted the measured amplitudes of  $\delta I$  as a function of echo number  $n$  for an Al-Pb junction at various temperatures at constant microwave power and constant applied bending moment. The theoretical lines were fitted to the experimental points as discussed in Sec. IV.

#### IV. COMPARISON OF EXPERIMENT WITH THEORY

In this section we give a detailed analysis of the data. The aluminum films used in these experiments were granular films<sup>16</sup> with normal resistivities in the range  $10^{-5}$ – $10^{-4}$   $\Omega\text{ cm}$  and coherence distances  $\xi_{\text{Al}} \approx l \leq 150$   $\text{\AA}$ . The value of the wave number  $q$  in aluminum<sup>17</sup> is  $q_{\text{Al}} = 9 \times 10^4 \text{ cm}^{-1}$ , and thus in the case of aluminum,  $q\xi \ll 1$  and we expect  $\delta I$  to be given by  $\delta I_s$ . For lead, on the other hand, the coherence distance<sup>10</sup>  $\xi_{\text{Pb}} = 830$   $\text{\AA}$ , the wave number<sup>17</sup>  $q_{\text{Pb}} = 2.9 \times 10^5 \text{ cm}^{-1}$  and hence  $q\xi > 1$ . Thus in the case of lead we shall assume that  $\delta I$  is given by  $\delta I_q$ . The total excess current  $\delta I$  is then given by

$$\delta I = \delta I_s(\text{Al}) + \delta I_q(\text{Pb}). \quad (15)$$

The characteristic features of the measured  $\delta I$  (see Fig. 5) is a relatively flat portion at low echo numbers and a pronounced maximum at higher echo numbers. Such a behavior is indeed predicted by the theory. Inspection of Eq. (12) reveals a resonant peak for  $E_x$  and via Eq. (3) for  $\delta I_s$ . Thus  $\delta I$  in Eq. (15) consists of a resonant term and a constant contribution via  $\delta I_q$ . The experimentally observed shift of the resonant peak to lower echo numbers

with decreasing temperatures is also in agreement with the theoretical predictions. This follows qualitatively from the following facts: The peak in  $\delta I$  occurs at a  $q_s$ , which we denote by  $q_{\text{sm}}$  and which is given approximately by [see Eq. (12)]

$$q_{\text{sm}}^2 = \text{Re}(\gamma_p^2). \quad (16)$$

The wave number  $\gamma_p$  can be expressed in terms of the complex conductivity  $\sigma = \sigma_1 - i\sigma_2$  [see Eqs. (21) and (A21)]. With decreasing temperature,  $\sigma_2$  increases,  $\text{Re}(\gamma_p^2)$  decreases, and thus  $n$  decreases [see Eq. (14)]. We also find that at a fixed temperature the peak shifts to lower echo number with increasing bending moment (see Fig. 4). Increasing the bending moment increases  $\theta_1$ , and to satisfy Eq. (16) for a fixed  $\gamma_p$ ,  $n$  has to decrease.

The main discrepancy between theory and experiment is that at larger echo numbers experimentally,  $\delta I$  is observed to decrease, whereas Eq. (15) predicts a constant value. The cause for this discrepancy is that attenuation of the sound beam was not taken into account. The attenuation is primarily due to the fact that by deflecting the sound beam by an angle  $\theta_n$ , part of the beam is not going to strike the junction area. After each round trip the center of the sound beam is displaced by an amount  $4d_0\theta_1$ .

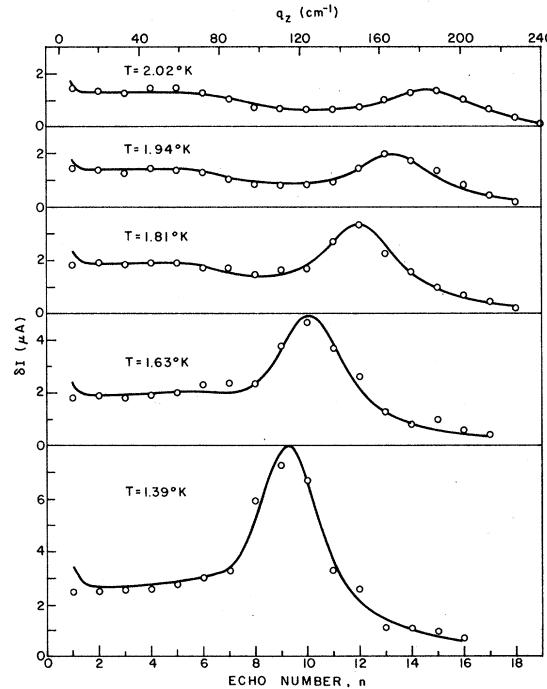


FIG. 5. The extra tunneling current  $\delta I$  for an Al-Pb junction plotted as a function of echo number  $n$  (lower scale) and wave number  $q_z$  (upper scale) at various temperatures and at constant microwave power and applied bending moment. The experimental results are given by the circles. The theoretical curves were calculated from Eq. (19).

$\times(n-1)$  from its previous position, where  $d_0$  is the length of the crystal. For a bending moment along the  $y$  axis, the total displacement  $z_n$  along the  $z$  direction is given by

$$z_n = 2n(n-1)d_0\theta_1. \quad (17)$$

The junctions used in the experiment were about 0.27 cm long and 0.1 cm wide with the longer dimension along the  $z$  axis. The edge of the junction came to about 0.015 cm from the edge of the crystal. As the center of the sound beam is displaced along the  $z$  direction, one expects an attenuation in  $\delta I$  once the trailing edge of the beam starts to recede from the junction area. This will occur after the center of the beam is deflected by approximately 0.015 cm. The echo at which this occurs we denote by  $n_1$ . After the beam is deflected by an additional 0.27 cm, no sound energy is incident on the junction surface and we expect a cutoff in  $\delta I$ . To allow for this attenuation,  $\delta I$  in Eq. (15) must be multiplied by an attenuation factor  $g(n)$ . We approximated  $g(n)$  by a decreasing exponential for  $n > n_1$  and by a constant for smaller  $n$ ,

$$g(n) = \begin{cases} 1 & \text{for } n \leq n_1 \\ e^{-b(n-n_1)} & \text{for } n > n_1, \end{cases} \quad (18)$$

where  $b$  is an adjustable parameter. Accordingly we set

$$\delta I = g[\delta I_s(\text{Al}) + \delta I_q(\text{Pb})]. \quad (19)$$

Inspection of the data of Fig. 5 shows that up to the sixth echo,  $\delta I$  is essentially unattenuated and accordingly we take  $n_1 = 6$ . The only temperature-dependent parameters entering the theory are  $\gamma_p$ ,  $\delta I_q(\text{Pb})$ , and  $f$ . The coefficient  $f$  was determined from the dc  $I$ - $V$  characteristics, while the other two were used as parameters in fitting Eq. (19) to the experimental data. The value of the parameter  $b$  was found to be 0.21 and  $|Cs_0|_{\text{Al}} = 18 \mu\text{eV}$ . The theoretical curves are plotted in Fig. 5 as a function of  $q_s$ . The proportionality factor between  $q_s$  and  $n$  [see Eq. (14)], obtained from the fit, is  $2q\theta_1 = 13 \text{ cm}^{-1}$ . Writing

$$\gamma_p = \alpha_p(1 - i/Q), \quad (20)$$

we found that the best fit between theory and experiment is obtained using  $Q = 9$  independent of temperature. The values of  $\alpha_p$  are plotted in Fig. 6 (points) as a function of the reduced temperature  $T/T_c$ . The general form of  $\gamma_p$  is given by Eq. (A19) in the Appendix. For the special case of a thin aluminum film,  $|K_{\text{Al}}d_{\text{Al}}| \ll 1$ , and a thick lead film,  $|K_{\text{Pb}}d_{\text{Pb}}| \gg 1$ , Eq. (A19) reduces to

$$\gamma_p = (\epsilon\omega^2/c^2)^{1/2}[1 + (i/wK_{\text{Pb}}) + (1/wd_{\text{Al}}K_{\text{Al}}^2)]^{1/2}, \quad (21)$$

where  $K$  is given by Eq. (A21). The theoretical curve in Fig. 6 was calculated from Eqs. (21) and

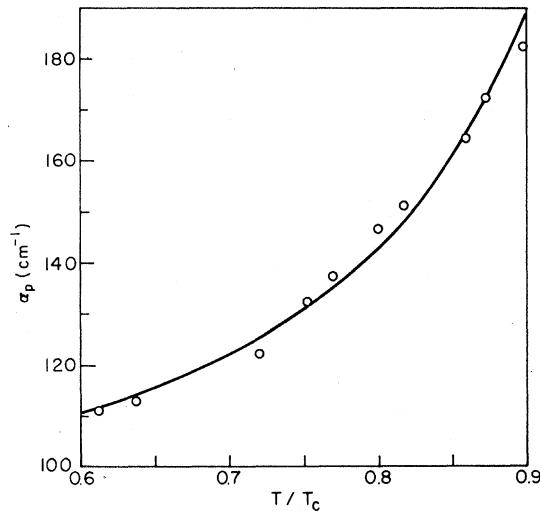


FIG. 6. The real part  $\alpha_p$  of the electromagnetic wave number in the strip line as a function of the reduced temperature  $T/T_c$  of Al. The circles represent the values used in fitting Eq. (19) to the experimental results in Fig. 5. The transition temperature  $T_c$  of Al was  $2.26^\circ\text{K}$ .

(A21) using the values for  $\sigma/\sigma_n$  from Mattis and Bardeen's theory,<sup>18</sup> where  $\sigma_n$  is the normal conductivity. The thickness of the Al film was approximately 400 Å, its normal conductivity  $\sigma_n = 4 \times 10^4 \Omega^{-1} \text{cm}^{-1}$ , the oxide thickness  $w$  and the dielectric constant  $\epsilon$ , this is in good agreement with the experimental value of  $\alpha_p = 173 \text{ cm}^{-1}$ . If we use, on the other hand, the formula for dirty superconductors,<sup>20</sup>

$$\sigma_2/\sigma_n = \left(\frac{1}{0.64}\right)^2 \pi \Delta(0) (T_c - T)/T_c \hbar \nu, \quad (22)$$

where  $\Delta(0)$  is the energy gap of Al at  $T=0$ , we obtain  $\alpha_p = 191 \text{ cm}^{-1}$ .

The quality factor  $Q$  in Eq. (20) is given by  $Q \approx 2\sigma_2/\sigma_1$  [see Eqs. (21) and (A21)]. At  $T/T_c = 0.87$ , the theoretical value of  $Q$  is 14 and increases to 54 at  $T/T_c = 0.62$ . The experimental value of  $Q = 9$  indicates that there is an additional contribution to the imaginary part of  $\gamma_p$ .

The fitted values of  $\delta I_q(\text{Pb})$  are plotted as a function of temperature in Fig. 7. The observed temperature dependence of  $\delta I_q(\text{Pb})$  follows closely that of  $f(T)$  and is in reasonable agreement with Cohen's calculations. The magnitude of  $\delta I_q(\text{Pb})$  is in an order-of-magnitude agreement with that calculated for Pb-Pb tunnel junctions.<sup>12</sup>

The bending angle  $\theta_1$  can be calculated from Eq. (14) and the experimental value of the proportional-

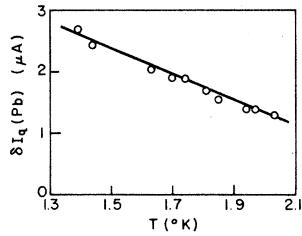


FIG. 7. The extra tunneling current  $\delta I_q$  due to the Pb film as a function of temperature. The circles represent the values used in fitting Eq. (19) to the experimental results in Fig. 5.

ity constant between  $q_s$  and the echo number  $n$ . The value obtained in this manner is 14.5 sec. Inserting this value for  $\theta_1$  into Eq. (17), we can calculate the echo number for which the edge of the sound beam starts to recede from the junction. We obtain that for  $z_n = 0.015$  cm,  $n = 7.7$ . This is consistent with the value of  $n_1 = 6$  estimated from Fig. 5.

The theoretical curves exhibit a small decrease going from the first to the second echo. This results from the contribution of  $E_s$  to  $\delta I_s$ . The expression for  $E_s$  is obtained from Eqs. (4) and (10) and is given by

$$E_s = 4(s_0 C) \sin(\frac{1}{2}q_s L) \sin(\frac{1}{2}q_s d)/q_s q_s L d, \quad (23)$$

where all the relevant quantities apply to Al. At low echo numbers,  $E_s$  is negligible, and thus  $\delta I_s$  is dominated by  $E_s$ . As  $E_s$  enters quadratically into Eq. (3) for  $\delta I_s$ , this contribution to the current will decrease approximately as  $\sin^2(\frac{1}{2}q_s)/(\frac{1}{2}q_s L)^2$  and is negligibly small after the first echo. In our measurements we did not resolve this structure.

## V. CONCLUSION

The possibility of adjusting the spatial variation of the strain in the films provided, in the present experiments, a means of distinguishing between the phonon-assisted tunneling current  $\delta I_q$  due to the nonlocal superconductor Pb and the strain-induced current  $\delta I_s$  due to the local superconductor Al. The good agreement between the experimental and theoretical results for  $\delta I_s$  provides firm evidence for the existence of an electric field outside the superconducting film proportional to the strain gradient  $\partial s/\partial z$ . This result is in agreement with the theories of Dressler,<sup>6</sup> Herring,<sup>7</sup> and Harrison<sup>21</sup> developed for the case of gravitation-induced strains, and thus provides an experimental confirmation. The absolute value of the deformation potential,  $C$ , in aluminum derived from the experimentally determined  $|Cs_0| = 18 \mu\text{eV}$  and strain<sup>22</sup>  $s_0 = (1 - 2) \times 10^{-6}$  is 9–18 eV. This value is in reasonable agreement with that deduced from Craig's data and is somewhat higher than the free-electron value of 8 eV.

## APPENDIX

To calculate  $E_x$  in the insulator we express the electric field  $\vec{E}$  and the magnetic field  $\vec{H}$  in terms of the vector potential  $\vec{A}$  and the scalar potential  $\varphi$ :

$$\vec{E} = -\frac{1}{c} \frac{\partial \vec{A}}{\partial t} - \vec{\Delta} \varphi, \quad (A1)$$

$$\vec{H} = \vec{\Delta} \times \vec{A}, \quad (A2)$$

where we choose the gauge

$$\vec{\Delta} \cdot \vec{A} = 0. \quad (A3)$$

In the two metals  $\varphi$  is given by Eqs. (4) and (6) in Sec. II, while in the insulator  $\varphi = 0$ . We denote the vector potential  $\vec{A}$  in the insulator by  $\vec{A}^{(0)}$  and in the two metals by  $\vec{A}^{(1)}$  and  $\vec{A}^{(2)}$ , respectively. After solving for  $\vec{A}^{(0)}$  we join the solutions in the different regions so as to satisfy the requirement of continuity of the tangential components of  $\vec{E}$  and  $\vec{H}$ . In the insulator  $\vec{A}$  is determined from the wave equation

$$\nabla^2 \vec{A}^{(0)} = \frac{\epsilon}{c^2} \frac{\partial^2 \vec{A}^{(0)}}{\partial t^2}, \quad (A4)$$

where  $\epsilon$  is the dielectric constant of the insulator. We seek wavelike solutions in the  $z$  direction of the form

$$\vec{A}^{(0)}(x, z, t) = \vec{A}^{(0)}(x) e^{i(\omega t - \gamma z)}, \quad (A5)$$

and because of the symmetry of the problem we take  $A_y = 0$ . Substituting  $\vec{A}^{(0)}$  from Eq. (A5) into Eq. (A4) yields

$$\frac{d^2 \vec{A}^{(0)}}{dx^2} - \Gamma^2 \vec{A}^{(0)} = 0, \quad (A6)$$

where

$$\Gamma^2 = \gamma^2 - (\epsilon \omega^2 / c^2). \quad (A7)$$

The general solution of Eq. (A6) is given by

$$\vec{A}^{(0)}(x) = \vec{R} e^{-\Gamma x} + \vec{S} e^{\Gamma x}, \quad (A8)$$

where the vectors  $\vec{R}$  and  $\vec{S}$  are integration constants. In order to satisfy Eq. (A3), the components of  $\vec{R}$  and  $\vec{S}$  must satisfy the relations

$$R_x = -i(\gamma/\Gamma)R_z, \quad (A9)$$

$$S_x = i(\gamma/\Gamma)S_z. \quad (A10)$$

Using Eqs. (A1) and (A2), the conditions of the continuity of the tangential components of  $\vec{E}$  and  $\vec{H}$  across the metal-insulator boundaries ( $x = \pm \frac{1}{2}w$ ) lead to the four relations

$$\left. \begin{aligned} \mathbf{G}_z^{(0)} &= \frac{c}{i\omega} \frac{\partial \phi^{(1)}}{\partial z} + \mathbf{G}_z^{(1)} \\ [\nabla \times \vec{\mathbf{G}}^{(0)}]_y &= [\nabla \times \vec{\mathbf{G}}^{(1)}]_y \end{aligned} \right\} x = \frac{1}{2}w, \quad (A11)$$

$$[\nabla \times \vec{\mathbf{G}}^{(0)}]_y = [\nabla \times \vec{\mathbf{G}}^{(1)}]_y, \quad (A12)$$

$$\left. \begin{aligned} \mathbf{G}_z^{(0)} &= \frac{c}{i\omega} \frac{\partial \phi^{(2)}}{\partial z} + \mathbf{G}_z^{(2)} \\ [\nabla \times \vec{\mathbf{G}}^{(0)}]_y &= [\nabla \times \vec{\mathbf{G}}^{(2)}]_y \end{aligned} \right\} x = -\frac{1}{2}w, \quad (A13)$$

$$[\nabla \times \vec{\mathbf{G}}^{(0)}]_y = [\nabla \times \vec{\mathbf{G}}^{(2)}]_y, \quad (A14)$$

where  $\phi^{(1)}$ ,  $\phi^{(2)}$  are the electrostatic potentials in metals 1, 2, respectively. In the metals the ratio  $\mathbf{G}_z/\mathbf{G}_y$  is of the order of  $|\gamma/K|$ , where  $K$  is the wave number of the electromagnetic wave in the metal. This follows from Eq. (A3) and the fact that in the metals  $\mathbf{G} \sim \exp[-i(Kx + qz)]$ . For the case treated here this ratio is negligible and thus to a very good approximation

$$\mathbf{G}_z^{(1)} / (\nabla \times \vec{\mathbf{G}}^{(1)})_y = (ic^2/4\pi\omega)Z_1, \quad x = \frac{1}{2}w \quad (A15)$$

$$\mathbf{G}_z^{(2)} / (\nabla \times \vec{\mathbf{G}}^{(2)})_y = -(ic^2/4\pi\omega)Z_2, \quad x = -\frac{1}{2}w, \quad (A16)$$

where  $Z_1$  and  $Z_2$  are the microwave surface impedances of the two metals. Combining Eqs. (4), (6), and (A9)–(A16) results in the two linear equations for  $R_z$  and  $S_z$ :

$$\begin{aligned} R_z & \left( 1 + \frac{i\epsilon\omega Z_1}{4\pi\Gamma} \right) e^{-\Gamma w/2} + S_z \left( 1 - \frac{i\epsilon\omega Z_1}{4\pi\Gamma} \right) e^{\Gamma w/2} \\ & = -q_z (Cs_0)_1 \frac{c}{e\omega} e^{i(r-q_z)x}, \end{aligned} \quad (A17)$$

$$\begin{aligned} R_z & \left( 1 - \frac{i\epsilon\omega Z_2}{4\pi\Gamma} \right) e^{\Gamma w/2} + S_z \left( 1 + \frac{i\epsilon\omega Z_2}{4\pi\Gamma} \right) e^{-\Gamma w/2} \\ & = -q_z (Cs_0)_2 \frac{c}{e\omega} e^{i(r-q_z)x}. \end{aligned} \quad (A18)$$

In deriving the last two equations we have neglected

<sup>1</sup>E. Lax and F. L. Vernon, Jr., Phys. Rev. Letters 14, 256 (1965).

<sup>2</sup>Y. Goldstein and B. Abeles, Phys. Letters 14, 78 (1965).

<sup>3</sup>B. Abeles and Y. Goldstein, Phys. Rev. Letters 14, 595 (1965); Y. Goldstein, B. Abeles, and R. W. Cohen, Phys. Rev. 151, 349 (1966).

<sup>4</sup>Y. Goldstein, M. Cohen, and B. Abeles, Phys. Rev. Letters 25, 1571 (1970).

<sup>5</sup>F. C. Witteborn and W. M. Fairbank, Phys. Rev. Letters 19, 1049 (1967); Nature 220, 436 (1968).

<sup>6</sup>A. J. Dessler, F. C. Michel, H. E. Rorschach, and G. T. Trammell, Phys. Rev. 168, 737 (1968).

<sup>7</sup>C. Herring, Phys. Rev. 171, 1361 (1968).

<sup>8</sup>J. W. Beams, Phys. Rev. Letters 21, 1093 (1968).

<sup>9</sup>P. P. Craig, Phys. Rev. Letters 22, 700 (1969).

<sup>10</sup>For definition and values of  $\xi$  see, for instance, P. G. DeGennes, *Superconductivity of Metals and Alloys*

the small phase shift  $e^{iqw/2}$  across the insulator because  $wq \ll 1$ . Furthermore, since  $w\Gamma \ll 1$ , we shall in Eqs. (A17) and (A18) expand the factor  $e^{\pm\Gamma w/2}$  and retain only the first two terms.

The characteristic wave numbers of the strip line  $\gamma_1$  and  $\gamma_2$  are determined from the roots of the equation  $|D(\Gamma)| = 0$ , where  $|D(\Gamma)|$  is the determinant of the left-hand side of Eqs. (A17) and (A18):

$$\gamma_1^2 = \gamma_2^2 = \gamma_p^2 = (\epsilon\omega^2/c^2)[1 + ic^2(Z_1 + Z_2)/4\pi w\omega], \quad (A19)$$

where we have neglected  $(\epsilon\omega/4\pi\Gamma)^2 Z_1 Z_2$  with respect to unity. The microwave surface impedance  $Z$  of a metal film is given by

$$Z = 4\pi\omega \coth(iKd)/Kc^2, \quad (A20)$$

where  $d$  is the film thickness and  $K$  is the wave number of the electromagnetic wave. In terms of the complex conductivity  $\sigma$ , the wave number  $K$  can be expressed as

$$K^2 = 4\pi i\omega\sigma/c^2. \quad (A21)$$

The wave excited by the sound is obtained by looking for a particular solution of Eqs. (A17) and (A18). We set  $\gamma = q_z$  and solve for  $R_z$  and  $S_z$ . Substituting these values into Eqs. (A8)–(A10) we obtain  $A_x^{(0)}$ . Using Eqs. (A1) and (A5) we obtain

$$E'_x = [(Cs_0)_2 - (Cs_0)_1]q_z^2 \exp(-iq_z z)/we(q_z^2 - \gamma_p^2). \quad (A22)$$

Here we have neglected the small variation of  $E'_x$  with  $x$  within the oxide layer. The complete solution for  $E_x$  is given by the sum of  $E'_x$  from Eq. (A22) and the characteristic waves  $E_1 e^{i\gamma_1 x} + E_2 e^{-i\gamma_2 x}$ . The two coefficients  $E_1$  and  $E_2$  are determined by the requirement that  $\bar{H}^{(0)}$  vanish at the two ends of the strip line  $z = \pm \frac{1}{2}L$ . This is the proper boundary condition for an open-ended strip line. The resulting expression for  $E_x$  is given by Eq. (12) in Sec. II.

(Benjamin, New York, 1969).

<sup>11</sup>James C. Swihart, J. Appl. Phys. 32, 461 (1961); A. B. Pippard, Proc. Roy. Soc. (London) A191, 385, (1947); A191, 399 (1947); see also P. V. Mason and R. W. Gould, J. Appl. Phys. 40, 2039 (1969).

<sup>12</sup>R. W. Cohen, Phys. Letters A33, 271 (1970).

<sup>13</sup>A. H. Dayem and R. J. Martin, Phys. Rev. Letters 8, 246 (1962).

<sup>14</sup>P. K. Tien and J. P. Gordon, Phys. Rev. 129, 647 (1963).

<sup>15</sup>The capacitive time constant is  $\tau = \epsilon r a / 4\pi w$ , where  $r$  is the tunneling resistance, and the remaining quantities are defined in the text. Substituting for the above quantities from Sec. III and IV and using a typical value  $r = 5 \Omega$ , we calculate  $\tau \approx 10^{-7}$  sec and thus  $\omega\tau \approx 10^4$ .

<sup>16</sup>Details of the preparation of the granular aluminum films and their normal and superconducting properties are given by R. W. Cohen and B. Abeles, Phys. Rev.

168, 444 (1968).

<sup>17</sup>Calculated from the elastic constant  $C_{11}$  of aluminum, P. M. Sutton, Phys. Rev. 91, 816 (1953); and lead, E. H. Swift and E. P. T. Tyndall, *ibid.* 61, 359 (1942).

<sup>18</sup>D. C. Mattis and J. Bardeen, Phys. Rev. 111, 412 (1958).

<sup>19</sup>We have determined  $\epsilon$  from the index of refraction of  $\text{Al}_2\text{O}_3$  given in *American Institute of Physics Handbook* (McGraw-Hill, New York, 1957), Chap. 6, p. 24.

<sup>20</sup>Equation (22) is derived by expressing in Eq. (A21) the quantity  $K$  in terms of the penetration depth of a dirty superconductor (see, for instance, Ref. 10, p. 225).

<sup>21</sup>W. A. Harrison, Phys. Rev. 180, 1606 (1969).

<sup>22</sup>The strain  $s_0$  was determined from the measured conversion efficiency of microwave power to acoustic power. The uncertainty in  $s_0$  reflects the uncertainty in the conversion efficiency.

## "Intermediate Mixed" State of Type-II Superconductors\*

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For magnetic fields in the range  $(1-D)H_{c1} < H < H_t$ , magnetization curves of low- $\kappa$  type-II Pb-In and In-Bi alloys with nonzero demagnetization coefficients  $D$  exhibit a linear dependence of the magnetic moment on applied field.  $H_{c1}$  is the lower critical field and  $H_t$  is the field at which this linear dependence terminates. For finite  $D$ ,  $H_t < H_{c1}$ . This behavior can be explained by a model of alternate regions of superconducting and mixed states. This array may be metastable. The mixed-state regions are all presumed to have the same temperature-dependent fluxoid-lattice spacing characteristic of  $H_{c1}$  when  $D=0$ . Thus, as the magnetic field is increased isothermally, the mixed-state regions grow until the whole sample has been converted into the mixed state. This model implies the existence of an attractive interaction between flux lines in low- $\kappa$  materials.

### I. INTRODUCTION

In a recent systematic study<sup>1</sup> of the effects of the demagnetization coefficient  $D$  on the magnetization curves of Pb-In and In-Bi alloys, we have verified the Cape-Zimmerman<sup>2</sup> equation

$$-4\pi(dM/dH)_{H_{c2}} = [\beta(2\kappa_2^2 - 1) + D]^{-1}, \quad (1)$$

where  $\beta$  is a constant taken to be 1.16 for a triangular flux lattice<sup>3</sup> and  $\kappa_2$  is the generalized Ginzburg-Landau (GL) parameter. Another generalized GL parameter  $\kappa_1$  was also obtained as a function of temperature and composition by using the Maki<sup>4</sup> results

$$H_c = H_{c2}/(\sqrt{2}\kappa_1), \quad (2)$$

where  $H_c$  is the thermodynamic critical field and  $H_{c2}$  is the upper critical field. Our measurements also indicated that  $\kappa_1 = \kappa_2$  for all compositions and temperatures studied, in agreement with the results of Kinsel, Lynton, and Serin<sup>5-7</sup> for In-Bi alloys with  $D=0$ . In the course of this work, we observed an "intermediate-state-like" behavior, similar to that seen in type-I superconductors, which is illustrated in Fig. 1. Both the low- $\kappa$  Pb-2 at. %

In and In-1.5 at. % Bi samples undergo an isothermal transition from type-I intermediate-state-like behavior to type-II behavior as the applied magnetic field is increased above some characteristic field  $H_t$ . This should not be confused with the observations of Kinsel *et al.*<sup>5-7</sup> on an In-1.5 at. % Bi sample which at higher temperatures exhibited type-I characteristics, but at lower temperatures demonstrated type-II behavior. Both of our samples also exhibited exclusively type-I behavior near  $T_c$ . At lower temperatures, the samples are type II for  $D=0$  (i.e.,  $\kappa > 0.71$ ). However, for a finite  $D$  they exhibit intermediate-state-like behavior over a certain region of applied field, i.e.,  $(1-D)H_{c1} < H < H_t$ , where  $H_{c1}$  is the lower critical field and  $H_t$  is the field at which the sample has fully transformed into the mixed state. As we shall show below,  $H_t < H_{c1}$  for finite  $D$ . Kinsel *et al.*<sup>5-7</sup> did not observe this latter effect because their samples were measured in a longitudinal field and thus demagnetization effects were absent.

There are electron-microscope measurements on these and similar alloy systems which bear directly on the interpretation of our macroscopic magnetization measurements. Thus, it is neces-

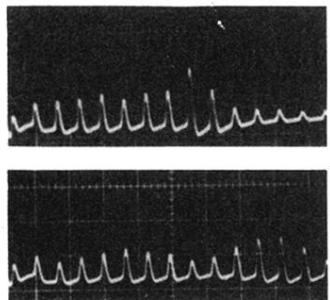


FIG. 4. Two oscillograms taken on the same junction at constant microwave power and temperature  $T = 1.36^{\circ}\text{K}$ . The upper one was taken with a bending moment applied to the quartz rod larger than that for the lower oscillogram. The horizontal scale is 10  $\mu\text{sec}/\text{div}$ .